

STD70N2LH5 STU70N2LH5

N-channel 25 V, 0.006 Ω 48 A - DPAK - IPAK STripFET™ V Power MOSFET

Preliminary Data

Features

Туре	V _{DSS}	R _{DS(on)} max	I _D
STD70N2LH5	25 V	0.0071 Ω	48 A
STU70N2LH5	25 V	$0.0075~\Omega$	48 A

- R_{DS(on)} * Q_g industry benchmark
- Extremely low on-resistance R_{DS(on)}
- Very low switching gate charge
- High avalanche ruggedness
- Low gate drive power losses

Application

Switching applications

Description

This product utilizes the 5th generation of design rules of ST's proprietary STripFETTM technology. The lowest available $R_{DS(on)}^*Q_g$, in the standard packages, makes this device suitable for the most demanding DC-DC converter applications, where high power density is to be achieved.

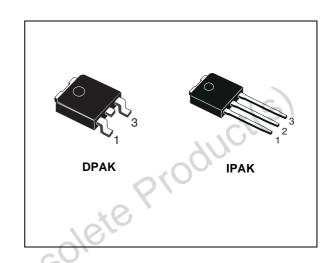


Figure 1. Internal schematic diagram

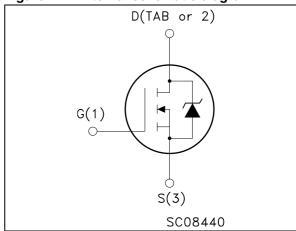


Table 1. Device summary

Order codes	Marking	Package	Packaging
STD70N2LH5	70N2LH5	DPAK	Tape & reel
STU70N2LH5	70N2LH5	IPAK	Tube

1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{DS}	Drain-source voltage (V _{GS} =0)	25	V
V _{GS}	Gate-Source voltage	± 22	V
I _D ⁽¹⁾	Drain current (continuous) at T _C = 25 °C	48	Α
I _D	Drain current (continuous) at T _C = 100 °C	43	A
I _{DM} ⁽²⁾	Drain current (pulsed)	192	A
P _{TOT}	Total dissipation at T _C = 25 °C	60	W
	Derating factor	0.4	W/°C
E _{AS} (3)	Single pulse avalanche energy	TBD	mJ
T _j T _{stg}	Operating junction temperature Storage temperature	-55 to 175	°C

^{1.} Limited by wire bonding

Table 3. Thermal resistance

	Symbol	Parameter	Value	Unit
	Rthj-case	Thermal resistance junction-case max	2.5	°C/W
	Rthj-amb Thermal resistance junction-case max		100	°C/W
	T_j	Maximum lead temperature for soldering purpose	275	°C
Obsole				

^{2.} Pulse width limited by safe operating area

^{3.} Starting Tj = 25 °C, I_D = 24 A, V_{DD} = 12 V

2 Electrical characteristics

(T_{CASE} = 25°C unless otherwise specified)

Table 4. Static

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V _{(BR)DSS}	Drain-source breakdown Voltage	$I_D = 250 \ \mu\text{A}, \ V_{GS} = 0$	25			V
I _{DSS}	Zero gate voltage drain current (V _{GS} = 0)	V _{DS} = 25 V V _{DS} = 25 V, T _C = 125 °C			1 10	μ Α μ Α
I _{GSS}	Gate body leakage current (V _{DS} = 0)	V _{GS} = ± 22 V		(±100	nA
V _{GS(th)}	Gate threshold voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	1	90		٧
		V _{GS} = 10 V, I _D = 24 A SMD version		0.006	0.0071	Ω
Book	R _{DS(on)} Static drain-source on resistance	V _{GS} = 10 V, I _D = 24 A		0.0064	0.0075	Ω
□DS(on)		V _{GS} = 5 V, I _D = 24 A SMD version		0.008	0.01	Ω
		$V_{GS} = 5 \text{ V}, I_D = 24 \text{ A}$		0.0084	0.0104	Ω

Table 5. Dynamic

	Symbol	Parameter	Test conditions	Min	Тур.	Max.	Unit
Obsole	C _{iss} C _{oss} C _{rss}	Input capacitance Output capacitance Reverse transfer capacitance	V _{DS} =25 V, f=1 MHz, V _{GS} =0		1300 300 50		pF pF pF
	Q _g Q _{gs} Q _{gd}	Total gate charge Gate-source charge Gate-drain charge	V_{DD} =15 V, I_D = 48 A V_{GS} =5 V (Figure 3)		8 TBD TBD		nC nC nC
	Q _{gs1}	Pre V _{th} gate-to-source charge Post V _{th} gate-to-source charge	V_{DD} =15 V, I_{D} = 48 A V_{GS} =5 V (Figure 8)		TBD TBD		nC nC
	R _G	Gate input resistance	f=1 MHz gate bias Bias= 0 test signal level=20 mV open drain		1.1		Ω

3/12

Table 6. Switching on/off (resistive load)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
t _{d(on)} t _r	Turn-on delay time Rise time	V_{DD} =10 V, I_{D} = 24 A, R_{G} =4.7 Ω , V_{GS} = 10 V (Figure 2 and Figure 7)		TBD TBD		ns ns
t _{d(off)}	Turn-off delay time Fall time	V_{DD} =10 V, I_D = 24 A, R_G =4.7 Ω , V_{GS} = 10 V (Figure 2 and Figure 7)		TBD TBD		ns ns

Table 7. Source drain diode

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{SD}	Source-drain current			10,	48	Α
I _{SDM}	Source-drain current (pulsed) ⁽¹⁾				192	Α
V_{SD}	Forward on voltage	I _{SD} =24 A, V _{GS} =0			1.1	>
t _{rr}	Reverse recovery time	I _{SD} =48 A,		TBD		ns
Q_{rr}	Reverse recovery charge	di/dt =100 A/µs, V _{DD} =20 V, Tj = 25 °C		TBD		nC
I _{RRM}	Reverse recovery current	(Figure 4)		TBD		Α

^{1.} Pulsed: pulse duration = 300μs, duty cycle 1.5%

3 Test circuit

Figure 2. Switching times test circuit for resistive load

Figure 3. Gate charge test circuit

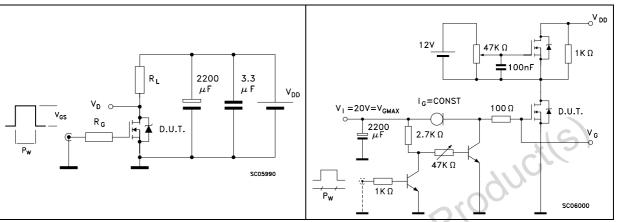


Figure 4. Test circuit for inductive load switching and diode recovery times

Figure 5. Unclamped Inductive load test circuit

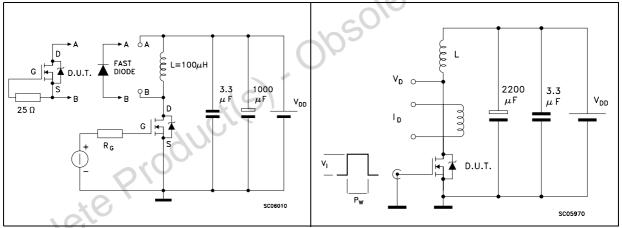


Figure 6. Unclamped inductive waveform

Figure 7. Switching time waveform

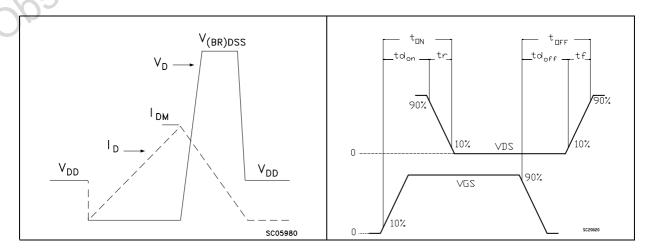
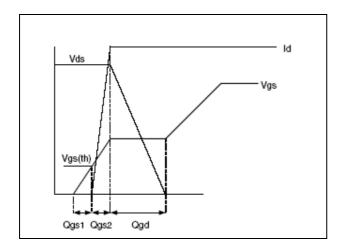


Figure 8. Gate charge waveform



Obsolete Product(s). Obsolete Product(s)

-

4 Package mechanical data

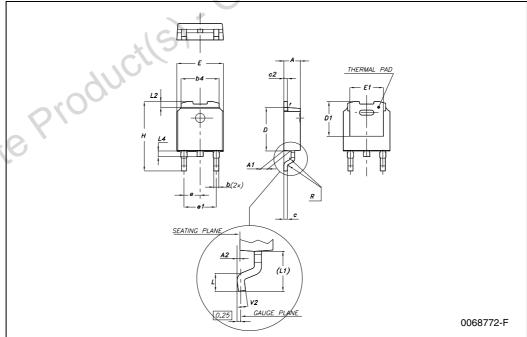
In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

Obsolete Product(s).

7/12

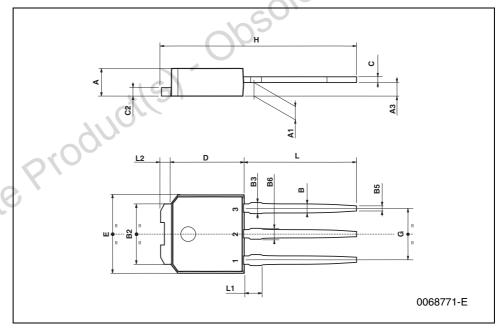
DPAK MECHANICAL DATA

DIM		mm.			inch		
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
Α	2.2		2.4	0.086		0.094	
A1	0.9		1.1	0.035		0.043	
A2	0.03		0.23	0.001		0.009	
В	0.64		0.9	0.025		0.035	
b4	5.2		5.4	0.204		0.212	
С	0.45		0.6	0.017		0.023	
C2	0.48		0.6	0.019		0.023	
D	6		6.2	0.236		0.244	
D1		5.1			0.200		
Е	6.4		6.6	0.252	1.11	0.260	
E1		4.7			0.185		
е		2.28			0.090		
e1	4.4		4.6	0.173		0.181	
Н	9.35		10.1	0.368	7	0.397	
L	1			0.039			
(L1)		2.8			0.110		
L2		0.8		U	0.031		
L4	0.6		40	0.023		0.039	
R		0.2	-103		0.008		
V2	0°		8°	0°		8°	



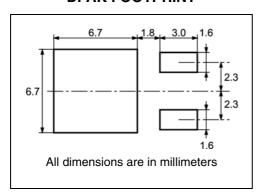
TO-251 (IPAK) MECHANICAL DATA

DIM.		mm			inch	
DIW.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
Α	2.2		2.4	0.086		0.094
A1	0.9		1.1	0.035		0.043
А3	0.7		1.3	0.027		0.051
В	0.64		0.9	0.025		0.031
B2	5.2		5.4	0.204		0.212
В3			0.85			0.033
B5		0.3			0.012	
В6			0.95			0.037
С	0.45		0.6	0.017		0.023
C2	0.48		0.6	0.019		0.023
D	6		6.2	0.236		0.244
E	6.4		6.6	0.252		0.260
G	4.4		4.6	0.173	5	0.181
Н	15.9		16.3	0.626		0.641
L	9		9.4	0.354		0.370
L1	0.8		1.2	0.031		0.047
L2		0.8	1	6	0.031	0.039

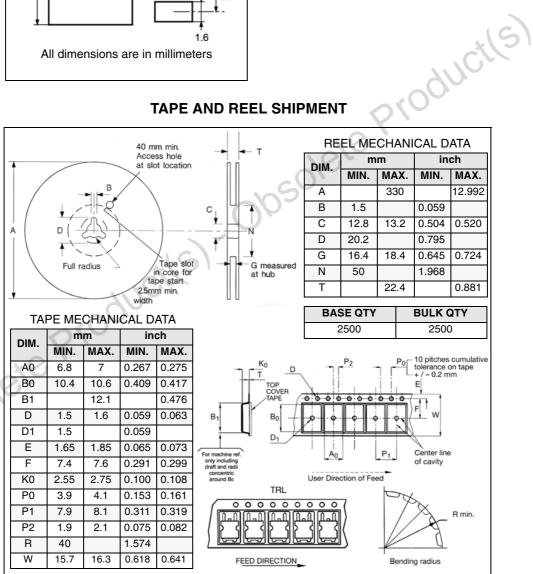


Packaging mechanical data 5

DPAK FOOTPRINT



TAPE AND REEL SHIPMENT



6 Revision history

Table 8. Document revision history

Date	Revision	Changes
16-Jan-2008	1	First release
23-Sep-2008	2	V _{GS} value has been changed on <i>Table 2</i> and <i>Table 5</i>

Obsolete Product(s). Obsolete Product(s)

Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZED ST REPRESENTATIVE, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2008 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for MOSFET category:

Click to view products by STMicroelectronics manufacturer:

Other Similar products are found below:

614233C 648584F MCH3443-TL-E MCH6422-TL-E FDPF9N50NZ FW216A-TL-2W FW231A-TL-E APT5010JVR NTNS3A92PZT5G IRF100S201 JANTX2N5237 2SK2464-TL-E 2SK3818-DL-E FCA20N60_F109 FDZ595PZ STD6600NT4G FSS804-TL-E 2SJ277-DL-E 2SK1691-DL-E 2SK2545(Q,T) D2294UK 405094E 423220D MCH6646-TL-E TPCC8103,L1Q(CM 367-8430-0972-503 VN1206L 424134F 026935X 051075F SBVS138LT1G 614234A 715780A NTNS3166NZT5G 751625C 873612G IRF7380TRHR IPS70R2K0CEAKMA1 RJK60S3DPP-E0#T2 RJK60S5DPK-M0#T0 APT5010JVFR APT12031JFLL APT12040JVR DMN3404LQ-7 NTE6400 JANTX2N6796U JANTX2N6784U JANTXV2N5416U4 SQM110N05-06L-GE3 SIHF35N60E-GE3